PCF8531

34 x 128 pixel matrix driver

Rev. 6 — 16 May 2011 Product data sheet

1. General description

The PCF8531 is a low-power CMOS[1] LCD row and column driver, designed to drive dot matrix graphic displays at multiplex rates of 1:17, 1:26, and 1:34. Furthermore, it can drive up to 128 icons. All necessary functions for the display are provided in a single chip, including on-chip generation of V_{LCD} and the LCD bias voltages, resulting in a minimum of external components and low power consumption. The PCF8531 is compatible with most microcontrollers and communicates via a two-line bidirectional I^2C-bus. All inputs are CMOS compatible.

Remark: The icon mode is used to reduce current consumption. When only icons are displayed, a much lower operating voltage (V_{LCD}) can be used and the switching frequency of the LCD outputs is reduced. In most applications it is possible to use V_{DD} as V_{LCD}.

2. Features and benefits

- Single-chip LCD controller and driver
- 34 row and 128 column outputs
- Display data RAM 34 × 128 bits
- 128 icons (last row is used for icons)
- Fast-mode I^2C-bus interface (400 kbit/s)
- Software selectable multiplex rates: 1:17, 1:26, and 1:34
- Icon mode with multiplex rate 1:2:
  - Featuring reduced current consumption while displaying icons only
- On-chip:
  - Generation of V_{LCD} (external supply also possible)
  - Selectable linear temperature compensation
  - Oscillator requires no external components (external clock also possible)
  - Generation of intermediate LCD bias voltages
  - Power-On Reset (POR)
- No external components required
- Software selectable bias configuration
- Logic supply voltage range V_{DD1} to V_{SS1}: 1.8 V to 5.5 V
- Supply voltage range for on-chip voltage generator V_{DD2} and V_{DD3} to V_{SS1} and V_{SS2}: 2.5 V to 4.5 V
- Display supply voltage range V_{LCD} to V_{SS}:
  - Normal mode: 4 V to 9 V

1. The definition of the abbreviations and acronyms used in this data sheet can be found in Section 19.

- Icon mode: 3 V to 9 V
- Low-power consumption, suitable for battery operated systems
- CMOS compatible inputs
- Manufactured in silicon gate CMOS process

3. Applications

- Telecommunication systems
- Automotive information systems
- Point-of-sale terminals
- Instrumentation

4. Ordering information

Table 1. Ordering information

Type number	Package		
	Name	Description	Version
PCF8531U/2DA/1	-	chip with bumps in tray	-

5. Block diagram

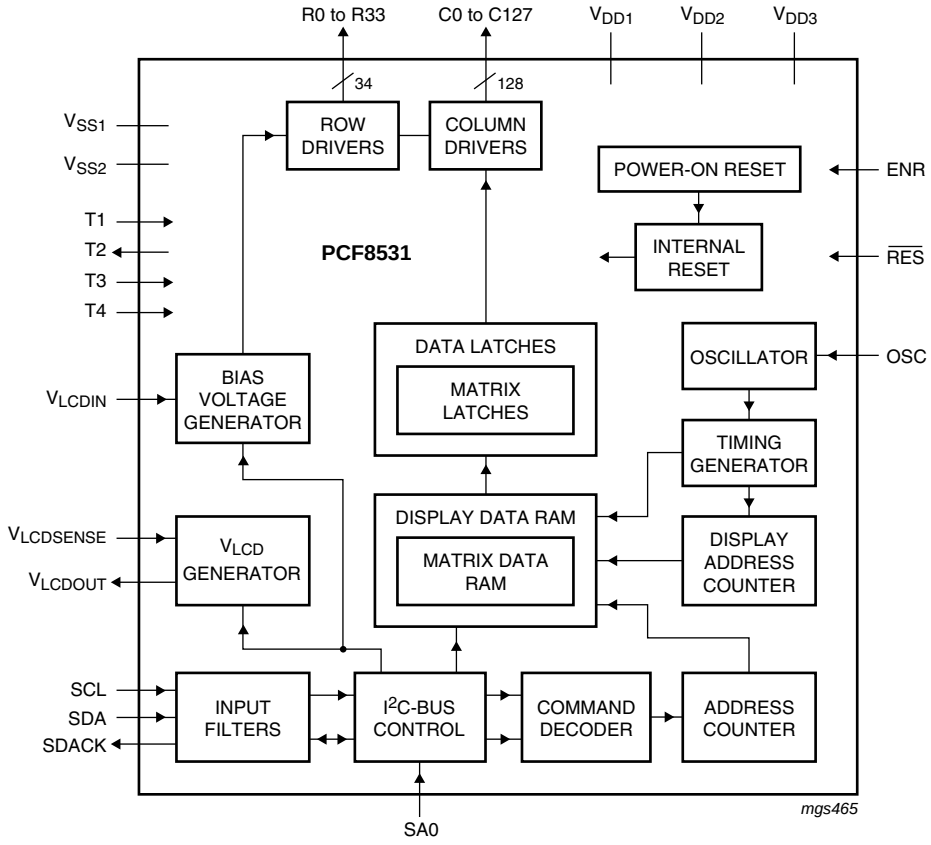
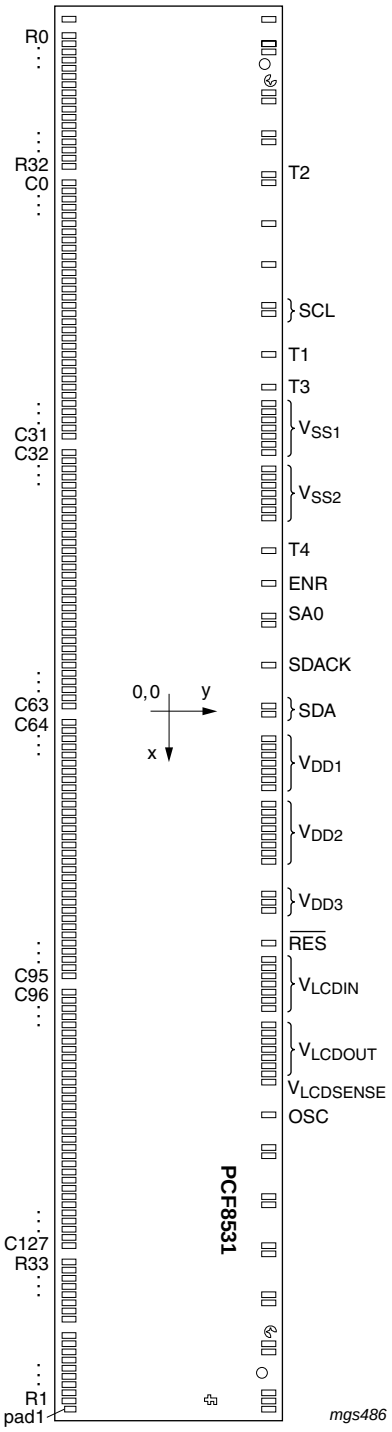


Fig 1. Block diagram of PCF8531

6. Pinning information

6.1 Pinning



Viewed from active side. The positioning of the bonding pads is not to scale.

Fig 2. Bonding pad location for PCF8531

Table 2. Pad allocation table

Pad	Symbol	Pad	Symbol
15	OSC	55	ENR
16	$V_{LCDSENSE}$	56	T4
17 to 23	V_{LCDOUT}	57 to 63	V_{SS2}
24 to 30	V_{LCDIN}	64 to 70	V_{SS1}
31	$\overline{RES}$	71	T3
32 to 34	V_{DD3}	72	T1
35 to 42	V_{DD2}	73 to 74	SCL
43 to 49	V_{DD1}	78	T2
50 to 51	SDA	87 to 103	R0, R2, R4, R6, R8, R10, R12, R14, R16, R18, R20, R22, R24, R26, R28, R30, R32
52	SDACK	104 to 231	C0 to C127
54	SA0	232 to 248	R33, R31, R29, R27, R25, R23, R21, R19, R17, R15, R13, R11, R9, R7, R5, R3, R1

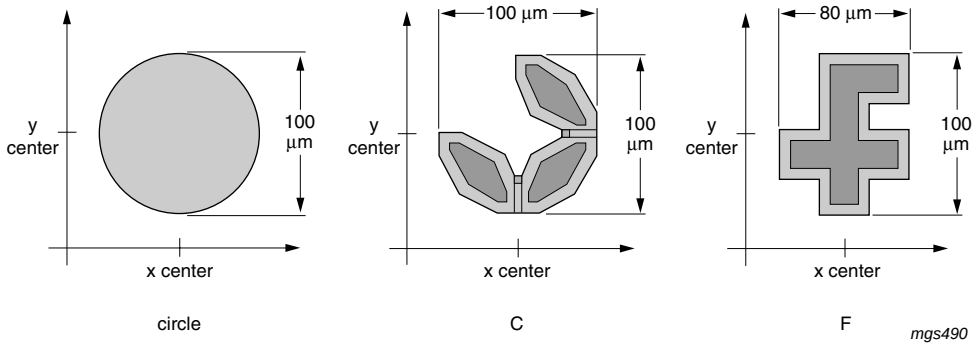


Fig 3. Alignment markers

Table 3. Alignment markers for PCF8531

All x/y coordinates represent the position of the center of each pad with respect to the center (x/y = 0) of the chip (see Figure 2).

Alignment marks	x (µm)	y (µm)
C1	−5402.0	823.1
C2	5292.4	950.0
F	5890.3	401.9
circle 1	−5543.0	798.4
circle 2	5637.4	798.4

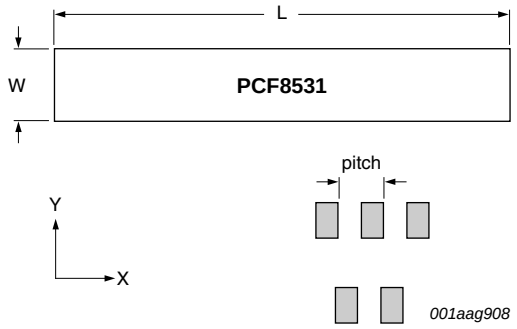


Fig 4. Chip dimensions

Table 4. Bonding pad dimensions

Pad	Size	Unit
pad pitch (minimum)	70	μm
bump dimensions	50 × 90 × 17.5 (±3)	μm
wafer thickness (excluding bumps)	381	μm
die size L × W	12.14 × 1.86[1]	mm

[1] Die size including saw lane of 70 μm.

6.2 Pin description

Table 5. Bonding pad description

All x/y coordinates represent the position of the center of each pad with respect to the center (x/y = 0) of the chip (see Figure 2).

Symbol	Pad	X (μm)	Y (μm)	Description	
-	1	5973.6	−821.7	dummy	
-	2	5969.5	823.4		
-	3	5899.5	823.4		
-	4	5829.5	823.4		
-	5	5479.5	823.4		
-	6	5409.5	823.4		
-	7	5059.5	823.4		
-	8	4989.5	823.4		
-	9	4639.5	823.4		
-	10	4569.5	823.4		
-	11	4219.5	823.4		
-	12	4149.5	823.4		
-	13	3799.5	823.4		
-	14	3729.5	823.4		
OSC	15	3449.5	823.4	oscillator input	[1]
$V_{LCDSENSE}$	16	3169.5	823.4	voltage multiplier regulation input (V_{LCD})	[2]

Table 5. Bonding pad description *...continued*

All x/y coordinates represent the position of the center of each pad with respect to the center (x/y = 0) of the chip (see Figure 2).

Symbol	Pad	X (μm)	Y (μm)	Description	
V_{LCDOUT}	17	3099.5	823.4	voltage multiplier output (V_{LCD})	[3]
V_{LCDOUT}	18	3029.5	823.4		
V_{LCDOUT}	19	2959.5	823.4		
V_{LCDOUT}	20	2889.5	823.4		
V_{LCDOUT}	21	2819.5	823.4		
V_{LCDOUT}	22	2749.5	823.4		
V_{LCDOUT}	23	2679.5	823.4		
V_{LCDIN}	24	2539.5	823.4	LCD supply voltage (V_{LCD})	[2]
V_{LCDIN}	25	2469.5	823.4		
V_{LCDIN}	26	2399.5	823.4		
V_{LCDIN}	27	2329.5	823.4		
V_{LCDIN}	28	2259.5	823.4		
V_{LCDIN}	29	2189.5	823.4		
V_{LCDIN}	30	2119.5	823.4		
$\overline{RES}$	31	1979.5	823.4	external reset input (active LOW)	[4]
V_{DD3}	32	1699.5	823.4	supply voltage 3	[5]
V_{DD3}	33	1629.5	823.4		
V_{DD3}	34	1559.5	823.4		
V_{DD2}	35	1279.5	823.4	supply voltage 2	[5]
V_{DD2}	36	1209.5	823.4		
V_{DD2}	37	1139.5	823.4		
V_{DD2}	38	1069.5	823.4		
V_{DD2}	39	999.5	823.4		
V_{DD2}	40	929.5	823.4		
V_{DD2}	41	859.5	823.4		
V_{DD2}	42	789.5	823.4		
V_{DD1}	43	649.5	823.4	supply voltage 1	[5]
V_{DD1}	44	579.5	823.4		
V_{DD1}	45	509.5	823.4		
V_{DD1}	46	439.5	823.4		
V_{DD1}	47	369.5	823.4		
V_{DD1}	48	299.5	823.4		
V_{DD1}	49	229.5	823.4		
SDA	50	19.5	823.4	serial data line input of the I^2C-bus	
SDA	51	−50.5	823.4		
SDACK	52	−400.5	823.4	serial data acknowledge output	[6]
-	53	−750.5	823.4	dummy	
SA0	54	−820.5	823.4	I^2C-bus slave address input; bit 0	
ENR	55	−1100.5	823.4	enable internal Power-On Reset (POR) input	[7]

Table 5. Bonding pad description *...continued*

All x/y coordinates represent the position of the center of each pad with respect to the center (x/y = 0) of the chip (see Figure 2).

Symbol	Pad	X (μm)	Y (μm)	Description	
T4	56	−1380.5	823.4	test input 4	[8]
V_{SS2}	57	−1660.5	823.4	ground 2	[9]
V_{SS2}	58	−1730.5	823.4		
V_{SS2}	59	−1800.5	823.4		
V_{SS2}	60	−1870.5	823.4		
V_{SS2}	61	−1940.5	823.4		
V_{SS2}	62	−2010.5	823.4		
V_{SS2}	63	−2080.5	823.4		
V_{SS1}	64	−2220.5	823.4	ground 1	[9]
V_{SS1}	65	−2290.5	823.4		
V_{SS1}	66	−2360.5	823.4		
V_{SS1}	67	−2430.5	823.4		
V_{SS1}	68	−2500.5	823.4		
V_{SS1}	69	−2570.5	823.4		
V_{SS1}	70	−2640.5	823.4		
T3	71	−2780.5	823.4	test 3	[8]
T1	72	−3060.5	823.4	test 1	[8]
SCL	73	−3410.5	823.4	serial clock line input of the I^2C-bus	
SCL	74	−3480.5	823.4		
-	75	−3830.5	823.4	dummy	
-	76	−4180.5	823.4		
-	77	−4530.5	823.4		
T2	78	−4600.5	823.4	test 2 output	[10]
-	79	−4880.5	823.4	dummy	
-	80	−4950.5	823.4		
-	81	−5230.5	823.4		
-	82	−5300.5	823.4		
-	83	−5650.5	823.4		
-	84	−5720.5	823.4		
-	85	−5930.5	823.4		
-	86	−5926.4	−821.7		
R0	87	−5786.4	−821.7	LCD row driver output	
R2	88	−5716.4	−821.7		
R4	89	−5646.4	−821.7		
R6	90	−5576.4	−821.7		
R8	91	−5506.4	−821.7		
R10	92	−5436.4	−821.7		

Table 5. Bonding pad description *...continued*

All x/y coordinates represent the position of the center of each pad with respect to the center (x/y = 0) of the chip (see Figure 2).

Symbol	Pad	X (μm)	Y (μm)	Description
R12	93	–5366.4	–821.7	LCD row driver output
R14	94	–5296.4	–821.7	
R16	95	–5226.4	–821.7	
R18	96	–5156.4	–821.7	
R20	97	–5086.4	–821.7	
R22	98	–5016.4	–821.7	
R24	99	–4946.4	–821.7	
R26	100	–4876.4	–821.7	
R28	101	–4806.4	–821.7	
R30	102	–4736.4	–821.7	
R32	103	–4666.4	–821.7	
C0	104	–4526.4	–821.7	LCD column driver output
C1	105	–4456.4	–821.7	
C2	106	–4386.4	–821.7	
C3	107	–4316.4	–821.7	
C4	108	–4246.4	–821.7	
C5	109	–4176.4	–821.7	
C6	110	–4106.4	–821.7	
C7	111	–4036.4	–821.7	
C8	112	–3966.4	–821.7	
C9	113	–3896.4	–821.7	
C10	114	–3826.4	–821.7	
C11	115	–3756.4	–821.7	
C12	116	–3688.4	–821.7	
C13	117	–3616.4	–821.7	
C14	118	–3546.4	–821.7	
C15	119	–3476.4	–821.7	
C16	120	–3406.4	–821.7	
C17	121	–3336.4	–821.7	
C18	122	–3266.4	–821.7	
C19	123	–3196.4	–821.7	
C20	124	–3126.4	–821.7	
C21	125	–3056.4	–821.7	
C22	126	–2986.4	–821.7	
C23	127	–2916.4	–821.7	
C24	128	–2846.4	–821.7	
C25	129	–2776.4	–821.7	
C26	130	–2706.4	–821.7	
C27	131	–2636.4	–821.7	

Table 5. Bonding pad description *...continued*

All x/y coordinates represent the position of the center of each pad with respect to the center (x/y = 0) of the chip (see Figure 2).

Symbol	Pad	X (μm)	Y (μm)	Description
C28	132	−2566.4	−821.7	LCD column driver output
C29	133	−2496.4	−821.7	
C30	134	−2426.4	−821.7	
C31	135	−2356.4	−821.7	
C32	136	−2216.4	−821.7	
C33	137	−2146.4	−821.7	
C34	138	−2076.4	−821.7	
C35	139	−2006.4	−821.7	
C36	140	−1936.4	−821.7	
C37	141	−1866.4	−821.7	
C38	142	−1796.4	−821.7	
C39	143	−1726.4	−821.7	
C40	144	−1656.4	−821.7	
C41	145	−1586.4	−821.7	
C42	146	−1516.4	−821.7	
C43	147	−1446.4	−821.7	
C44	148	−1376.4	−821.7	
C45	149	−1306.4	−821.7	
C46	150	−1236.4	−821.7	
C47	151	−1166.4	−821.7	
C48	152	−1096.4	−821.7	
C49	153	−1026.4	−821.7	
C50	154	−956.4	−821.7	
C51	155	−886.4	−821.7	
C52	156	−816.4	−821.7	
C53	157	−746.4	−821.7	
C54	158	−676.4	−821.7	
C55	159	−606.4	−821.7	
C56	160	−534.6	−821.7	
C57	161	−466.4	−821.7	
C58	162	−396.4	−821.7	
C59	163	−326.4	−821.7	
C60	164	−256.4	−821.7	
C61	165	−186.4	−821.7	
C62	166	−116.6	−821.7	
C63	167	−46.4	−821.7	
C64	168	93.6	−821.7	
C65	169	163.6	−821.7	
C66	170	233.6	−821.7	

Table 5. Bonding pad description *…continued*

All x/y coordinates represent the position of the center of each pad with respect to the center (x/y = 0) of the chip (see Figure 2).

Symbol	Pad	X (μm)	Y (μm)	Description
C67	171	303.6	–821.7	LCD column driver output
C68	172	373.3	–821.7	
C69	173	443.6	–821.7	
C70	174	513.6	–821.7	
C71	175	583.6	–821.7	
C72	176	653.6	–821.7	
C73	177	723.6	–821.7	
C74	178	793.6	–821.7	
C75	179	863.6	–821.7	
C76	180	933.6	–821.7	
C77	181	1003.6	–821.7	
C78	182	1073.6	–821.7	
C79	183	1143.6	–821.7	
C80	184	1213.6	–821.7	
C81	185	1283.6	–821.7	
C82	186	1353.6	–821.7	
C83	187	1423.6	–821.7	
C84	188	1493.6	–821.7	
C85	189	1563.6	–821.7	
C86	190	1633.6	–821.7	
C87	191	1703.6	–821.7	
C88	192	1773.6	–821.7	
C89	193	1843.6	–821.7	
C90	194	1913.6	–821.7	
C91	195	1983.6	–821.7	
C92	196	2053.6	–821.7	
C93	197	2123.6	–821.7	
C94	198	2193.6	–821.7	
C95	199	2263.6	–821.7	
C96	200	2403.6	–821.7	
C97	201	2473.6	–821.7	
C98	202	2543.6	–821.7	
C99	203	2613.6	–821.7	
C100	204	2683.6	–821.7	
C101	205	2753.6	–821.7	
C102	206	2823.6	–821.7	
C103	207	2893.6	–821.7	
C104	208	2963.6	–821.7	
C105	209	3033.6	–821.7	

Table 5. Bonding pad description *…continued*

All x/y coordinates represent the position of the center of each pad with respect to the center (x/y = 0) of the chip (see Figure 2).

Symbol	Pad	X (μm)	Y (μm)	Description
C106	210	3103.6	–821.7	LCD column driver output
C107	211	3173.6	–821.7	
C108	212	3243.6	–821.7	
C109	213	3313.6	–821.7	
C110	214	3383.6	–821.7	
C111	215	3453.6	–821.7	
C112	216	3523.6	–821.7	
C113	217	3593.6	–821.7	
C114	218	3663.6	–821.7	
C115	219	3733.6	–821.7	
C116	220	3803.6	–821.7	
C117	221	3873.6	–821.7	
C118	222	3943.6	–821.7	
C119	223	4013.6	–821.7	
C120	224	4083.6	–821.7	
C121	225	4153.6	–821.7	
C122	226	4223.6	–821.7	
C123	227	4293.6	–821.7	
C124	228	4363.6	–821.7	
C125	229	4433.6	–821.7	
C126	230	4503.6	–821.7	
C127	231	4573.6	–821.7	
R33	232	4713.6	–821.7	LCD row driver output; icon row
R31	233	4783.6	–821.7	LCD row driver output
R29	234	4853.6	–821.7	
R27	235	4923.6	–821.7	
R25	236	4993.6	–821.7	
R23	237	5063.6	–821.7	
R21	238	5113.6	–821.7	
R19	239	5203.6	–821.7	
R17	240	5343.6	–821.7	
R15	241	5413.6	–821.7	
R13	242	5483.6	–821.7	
R11	243	5553.6	–821.7	
R9	244	5623.6	–821.7	
R7	245	5693.6	–821.7	
R5	246	5763.6	–821.7	
R3	247	5833.6	–821.7	
R1	248	5903.6	–821.7	

[1] If the on-chip oscillator is used, this input must be connected to V_{DD1}.

[2] If the internal V_{LCD} generation is used, V_{LCDOUT}, V_{LCDIN}, and $V_{LCDSENSE}$ must be connected together.

[3] If an external V_{LCD} is used in the application, then pin V_{LCDOUT} must be left open-circuit, otherwise the chip will be damaged.

[4] If only the internal Power-On Reset (POR) is used, this input must be connected to V_{DD1}.

[5] V_{DD1} is for the logic supply, V_{DD2} and V_{DD3} are for the voltage multiplier. For split power supplies, V_{DD2} and V_{DD3} must be connected together. If only one supply voltage is available, V_{DD1}, V_{DD2}, and V_{DD3} must be connected together.

[6] Serial data acknowledge for the I^2C-bus. By connecting SDACK to SDA externally, the SDA line becomes fully I^2C-bus compatible. Having the acknowledge output separated from the serial data line is advantageous in Chip-On-Glass (COG) applications. In COG applications where the track resistance from the SDACK pad to the system SDA line can be significant, a potential divider is generated by the bus pull-up resistor and the Indium Tin Oxide (ITO) track resistance. It is possible that the PCF8531 will not be able to create a valid logic 0 level during the acknowledge cycle. By splitting the SDA input from the SDACK output, the device could be used in a mode that ignores the acknowledge bit. In COG applications where the acknowledge cycle is required, it is necessary to minimize the track resistance from the SDACK pad to the system SDA line to guarantee a valid LOW level.

[7] If ENR is connected to V_{SS}, Power-On Reset (POR) is disabled; to enable Power-On Reset (POR) ENR must be connected to V_{DD1}.

[8] In the application, this input must be connected to V_{SS}.

[9] V_{SS1} and V_{SS2} must be connected together.

[10] In the application, T2 must be left open-circuit.

7. Functional description

7.1 Oscillator

The on-chip oscillator provides the clock signal for the display system. No external components are required and the OSC input must be connected to V_{DD}. An external clock signal, if used, is connected to this input.

7.2 Power-On Reset (POR)

The on-chip Power-On Reset (POR) initializes the chip after power-on or power failure.

7.3 I²C-bus controller

The I²C-bus controller receives and executes the commands. The PCF8531 acts as an I²C-bus slave receiver and therefore it cannot control bus communication.

7.4 Input filters

To enhance noise immunity in electrically adverse environments, RC low-pass filters are provided on the SDA and SCL lines.

7.5 Display data RAM

The PCF8531 contains 34 × 128 bits static RAM for storing the display data, see Figure 7. The RAM is divided into 6 banks of 128 bytes (6 × 8 × 128 bits). Bank 5 is used for icon data. During RAM access, data is transferred to the RAM via the I²C-bus interface. There is a direct correspondence between the X address and column output number.

7.6 Timing generator

The timing generator produces the various signals required to drive the internal circuitry. Internal chip operation is not affected by operations on the data buses.

7.7 Address counter

The address counter sets the addresses of the display data RAM for writing.

7.8 Display address counter

The display address counter generates the addresses for read out of the display data.

7.9 Command decoder

The command decoder identifies command words that arrive on the I²C-bus and determines the destination for the following data bytes.

7.10 Bias voltage generator

The bias voltage generator generates four buffered intermediate bias voltages. This block contains the generator for the reference voltages and the four buffers. This block can operate in two voltage ranges:

- Normal mode: 4.0 V to 9.0 V
- Power save mode: 3.0 V to 9.0 V.

7.11 V_{LCD} generator

The V_{LCD} voltage generator contains a configurable 2 to 5 times voltage multiplier; this is programmed by software.

7.12 Reset

The PCF8531 has the possibility of two reset modes: internal Power-On Reset (POR) or external reset ($\overline{RES}$). The reset mode is selected using the ENR signal. After a reset, the chip has the following state:

- All row and column outputs are set to V_{SS} (display off)
- RAM data is undefined
- Power-down mode

7.13 Power-down

During power-down, all static currents are switched off (no internal oscillator, no timing and no LCD segment drive system) and all LCD outputs are internally connected to V_{SS}. The I^2C-bus function remains operational.

7.14 Column driver outputs

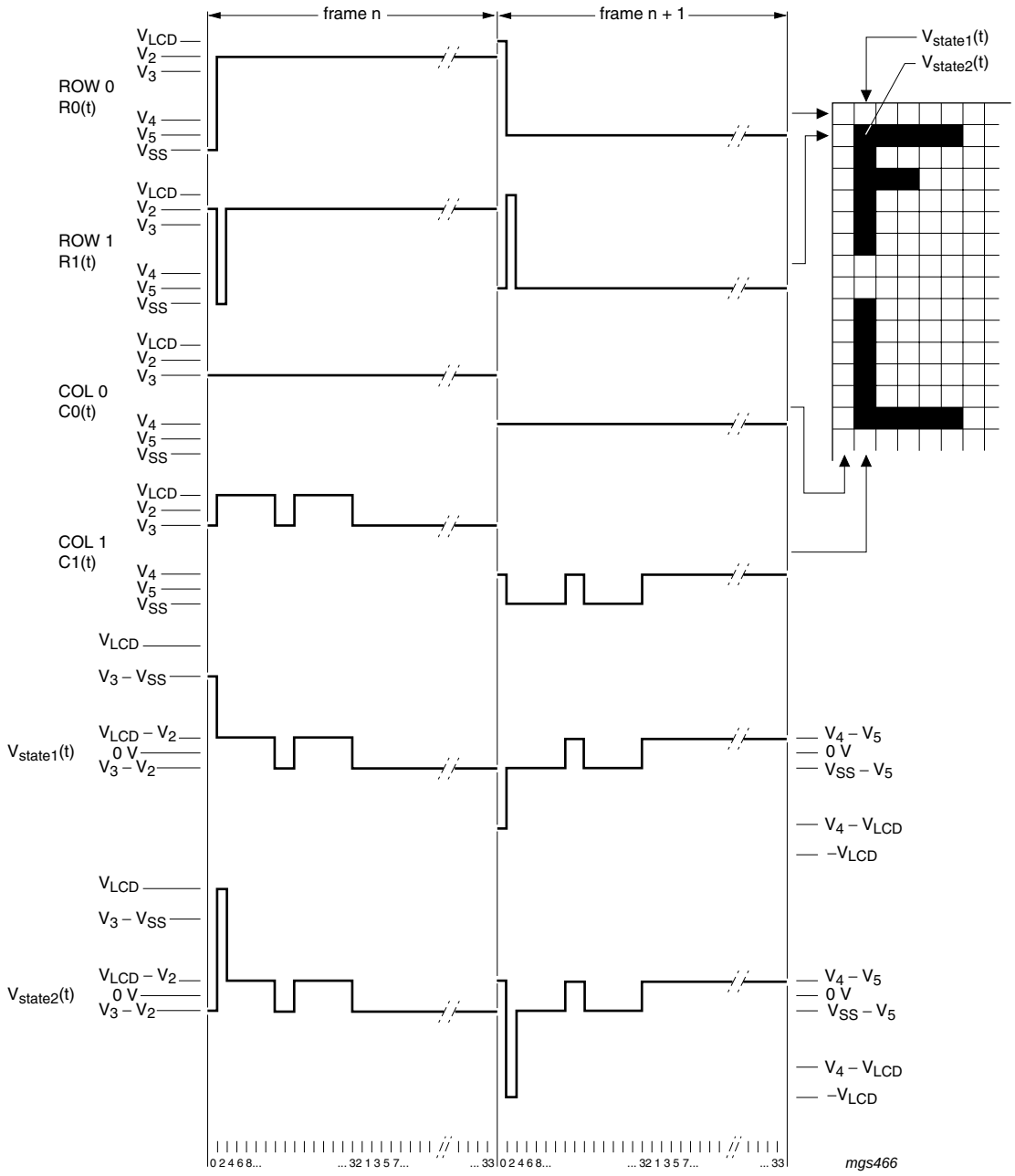
The LCD drive section includes 128 column outputs (C0 to C127) which must be connected directly to the LCD. The column output signals are generated in accordance with the multiplexed row signals and with the data in the display latch. When less than 128 columns are required, the unused column outputs must be left open-circuit.

7.15 Row driver outputs

The LCD drive section includes 34 row outputs (R0 to R33), which must be connected directly to the LCD. The row output signals are generated in accordance with the selected LCD drive mode. If less than 34 rows or lower multiplex rates are required, the unused outputs must be left open-circuit. The row signals are interlaced i.e. the selection order is R0, R2, ..., R1, R3, etc.

8. LCD waveforms and DDRAM to data mapping

The LCD waveforms and the DDRAM to display data mapping are shown in Figure 5, Figure 6 and Figure 7.



(1) $V_{state1}(t) = C1(t) - R0(t)$.

(2) $V_{state2}(t) = C1(t) - R1(t)$.

Fig 5. Typical LCD driver waveforms

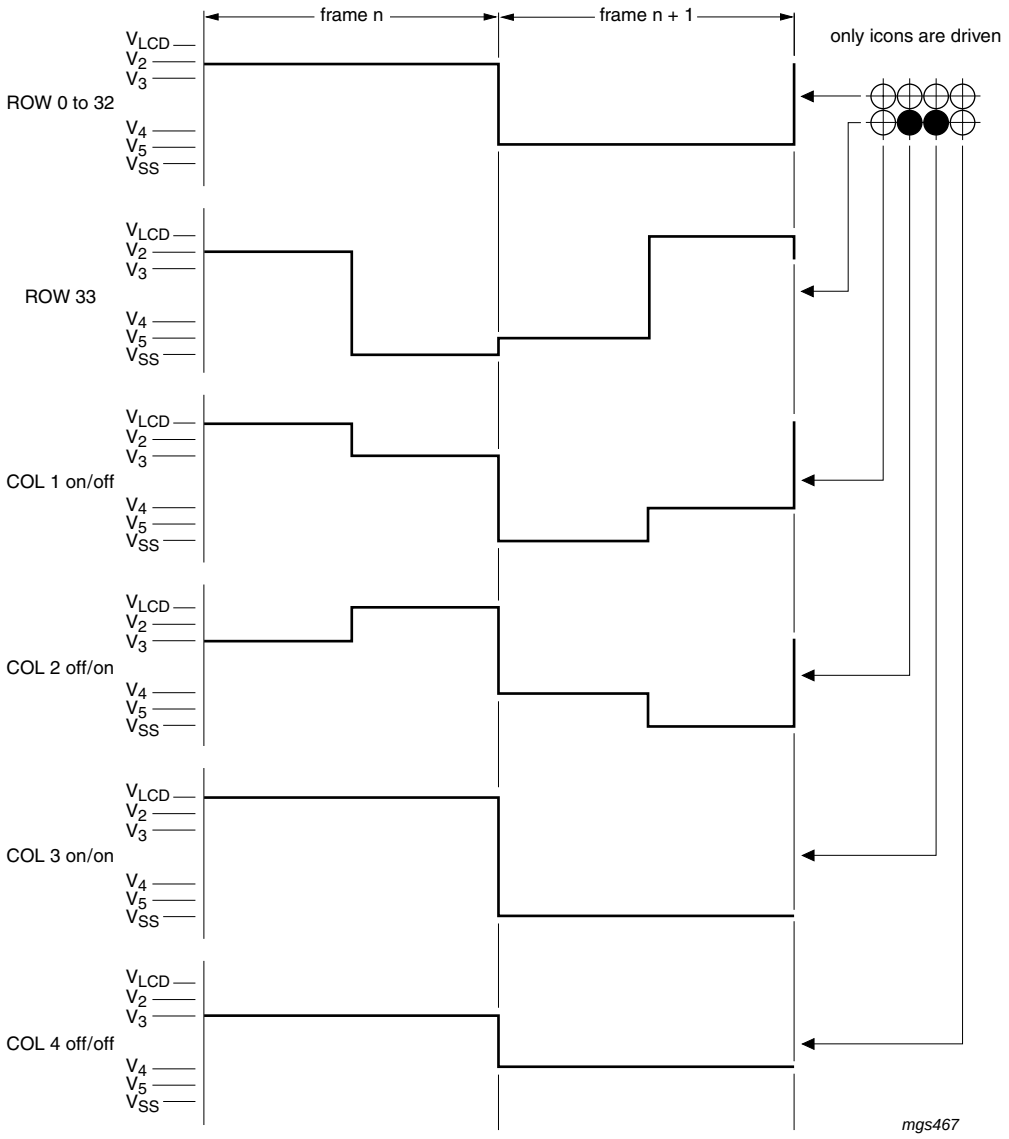


Fig 6. LCD waveforms, icon mode, multiplex rate 1:2

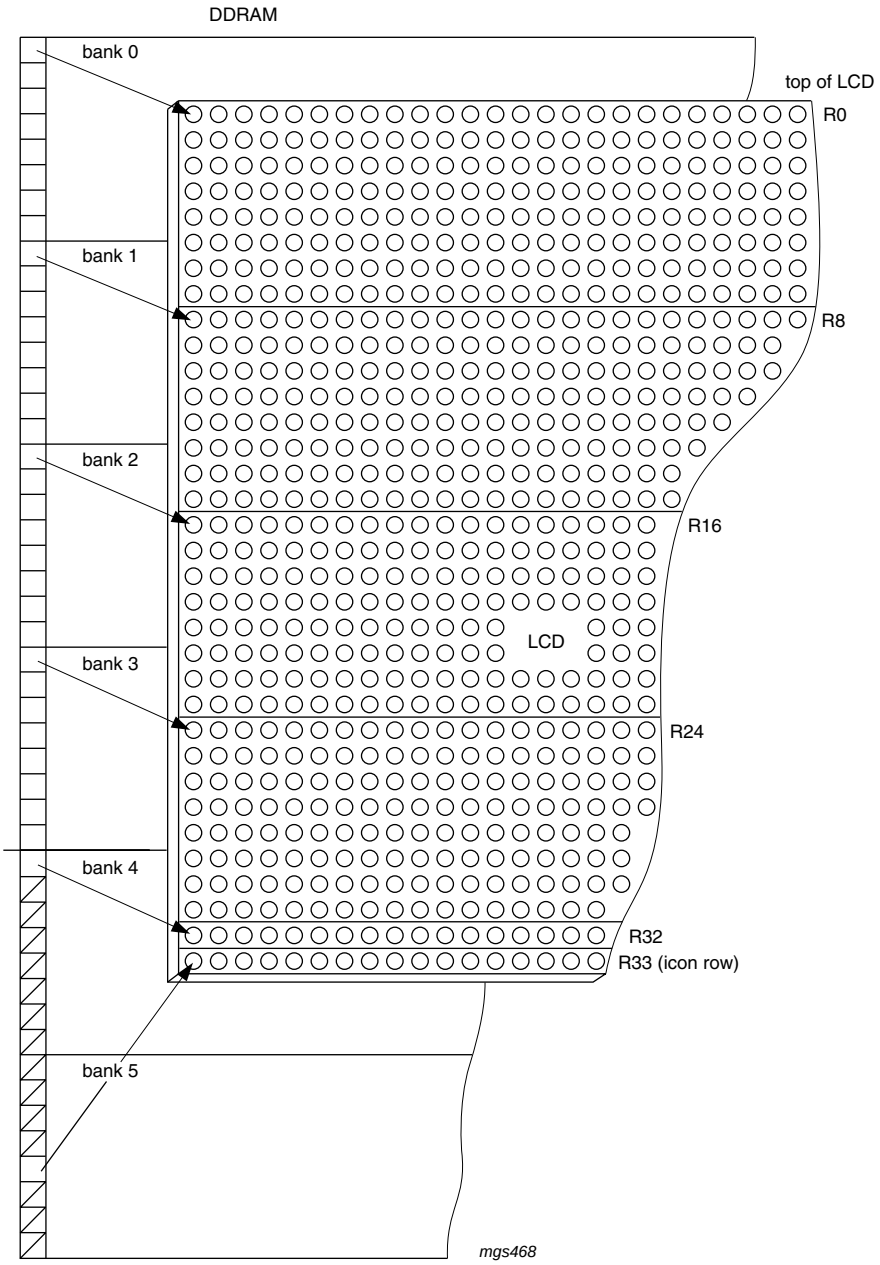


Fig 7. DDRAM to display data mapping

8.1 Addressing

Data is written in bytes into the RAM matrix of the PCF8531 as shown in Figure 8, Figure 9 and Figure 10. The display RAM has a matrix of 34 × 128 bits. The columns are addressed by the address pointer. The address ranges are X 0 to X 127 (7Fh) and Y 0 to Y 5 (5h). Addresses outside of these ranges are not allowed. In vertical addressing mode (V = 1), the Y address increments after each byte (see Figure 9). After the last Y address (Y = 4), Y wraps around to 0 and X increments to address the next column. In horizontal addressing mode (V = 0), the X address increments after each byte (see Figure 10). After the last X address (X = 127), X wraps around to 0 and Y increments to address the next

row. After the very last address (X = 127 and Y = 4), the address pointers wrap around to address (X = 0 and Y = 0). The Y address 5 is reserved for icon data and is not affected by the addressing mode. Please note that in bank 4 only the LSB (DB0) of the data is written into the RAM and in bank 5 only the 5th data bit (DB4) is written into the RAM.

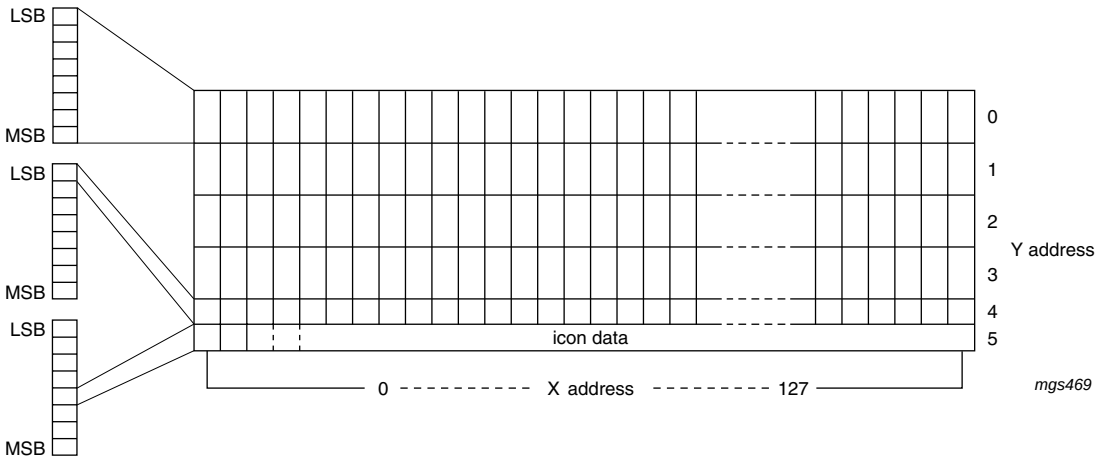


Fig 8. RAM format and addressing

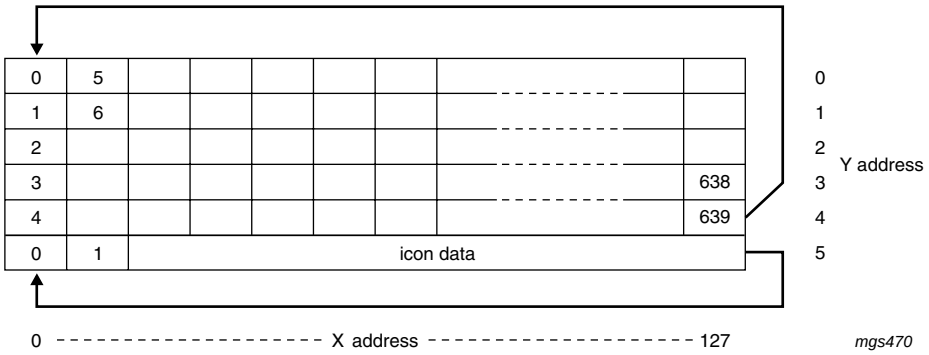


Fig 9. Sequence of writing data bytes into RAM with vertical addressing (V = 1)

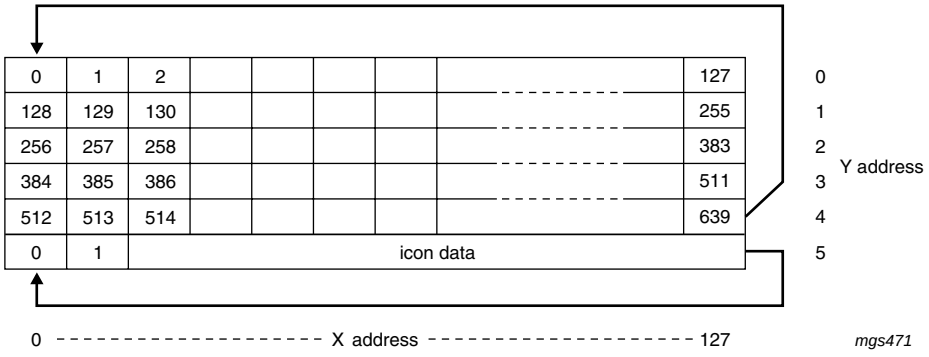


Fig 10. Sequence of writing data bytes into RAM with horizontal addressing (V = 0)

9. Instructions

Only two PCF8531 registers, the instruction register and the data register can be directly controlled by the MPU. Before internal operation, control information is stored temporarily in these registers to allow interfacing to various types of MPUs which operate at different speeds or to allow interfacing to peripheral control ICs. The PCF8531 operation is controlled by the instructions given in Table 11.

Instructions are of four types:

- Those that define PCF8531 functions e.g. display configuration, etc.
- Those that set internal RAM addresses
- Those that perform data transfer to/from the internal RAM
- Others

In normal mode instructions which perform data transfer to/from the internal RAM are used most frequently. Automatic incrementing by 1 of internal RAM addresses after each data write reduces the MPU program load.

9.1 Reset

After reset or internal Power-On Reset (POR) (depending on the application), the LCD driver is set to the following state:

- Power-down mode (PD = 1)
- Horizontal addressing (V = 0)
- Display blank (D = 0; E = 0), no icon mode (IM = 0)
- Address counter X[6:0] = 0; Y[2:0] = 0
- Bias system BS[2:0] = 0
- Multiplex rate M[1:0] = 0 (multiplex rate 1:17)
- Temperature control mode TC[2:0] = 0
- HV-gen control, HVE = 0 the high voltage (HV) generator is switched off, PRS = 0 and S[1:0] = 0
- V_{LCD} = 0 V
- RAM data is undefined
- Command page definition H[1:0] = 0

9.2 Function set

9.2.1 PD

When PD = 1, the power-down mode of the LCD driver is active:

- All LCD outputs at V_{SS} (display off)
- Power-On Reset (POR) detection active, oscillator off
- V_{LCD} can be disconnected
- I^2C-bus is operational, commands can be executed
- RAM contents not cleared; RAM data can be written
- Register settings remain unchanged

9.2.2 V

When V = 0 the horizontal addressing is selected. The data is written into the DDRAM as shown in Figure 10. When V = 1 the vertical addressing is selected. The data is written into the DDRAM as shown in Figure 9. Icon data is written independently of V when Y address is 5.

9.3 Set Y address

Bits Y2, Y1, and Y0 define the Y address vector of the display RAM (see Table 6).

Table 6. Y address

Y2	Y1	Y0	Bank
0	0	0	0
0	0	1	1
0	1	0	2
0	1	1	3
1	0	0	4
1	0	1	5 (icons)

9.4 Set X address

The X address points to the columns. The range of X is 0 to 127 (7Fh).

9.5 Set multiplex rate

M[1:0] selects the multiplex rate (see Table 7).

Table 7. Multiplex rates

Multiplex rate	M1	M0
1:17	0	0
1:26	1	0
1:34	0	1

9.6 Display control (D, E, and IM)

Bits D and E select the display mode (see Table 13). Bit IM (see Table 12) sets the display to icon mode.

9.7 Set bias system

The bias voltage levels are set in the ratio of R – R – n × R – R – R (see Figure 11).

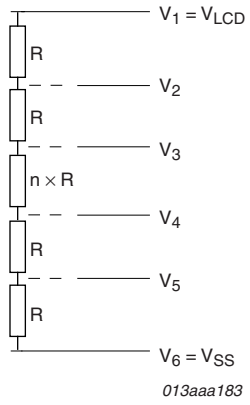


Fig 11. Voltage divider chain

Different multiplex rates require different bias settings. Bias settings are programmed by BS[2:0], which sets the binary number n. The optimum value for n is given by:

$$n = \sqrt{muxrate} - 3$$

Supported values of n are given in Table 8. Table 9 shows the intermediate bias voltages.

Table 8. Programming the required bias system

BS[2:0]	n	Bias system	Comment
000	7	1/11	-
001	6	1/10	-
010	5	1/9	-
011	4	1/8	-
100	3	1/7	recommended for 1:34
101	2	1/6	recommended for 1:26
110	1	1/5	recommended for 1:17
111	0	1/4	recommended for icon mode

9.8 LCD bias voltage

Table 9. Intermediate LCD bias voltages

Symbol	Bias voltage	Example for 1/7 bias
V1	V_{LCD}	V_{LCD}
V2	$\frac{n+3}{n+4} \times V_{LCD}$	$^6/_7 \times V_{LCD}$
V3	$\frac{n+2}{n+4} \times V_{LCD}$	$^5/_7 \times V_{LCD}$
V4	$\frac{2}{n+4} \times V_{LCD}$	$^2/_7 \times V_{LCD}$
V5	$\frac{1}{n+4} \times V_{LCD}$	$^1/_7 \times V_{LCD}$
V6	V_{SS}	V_{SS}

9.9 Set V_{LCD} value

V_{LCD} can be set by software. The voltage at intersection temperature [V_{LCD} ($T = T_{ints}$)] can be calculated as: $V_{LCD}(T_{ints}) = a + V_{LCD} \times b$

The generated voltage is dependent on the temperature, programmed Temperature Coefficient (TC) and the programmed voltage at intersection temperature (T_{ints}).

$V_{LCD} = V_{LCD}(T_{ints}) \times [1 + TC \times (T - T_{ints})]$

The parameter values are given in Table 10. Two overlapping V_{LCD} ranges can be selected via the command HV-gen control (see Table 10 and Figure 12). The maximum voltage which can be generated depends on the V_{DD2} and V_{DD3} voltages and the display load current. For multiplex rate 1:34, the optimum V_{LCD} can be calculated as:

$$V_{LCD} = \frac{1+\sqrt{34}}{\sqrt{2 \times \left(1 - \frac{1}{\sqrt{34}}\right)}} \times V_{th} = 5.30 \times V_{th}$$

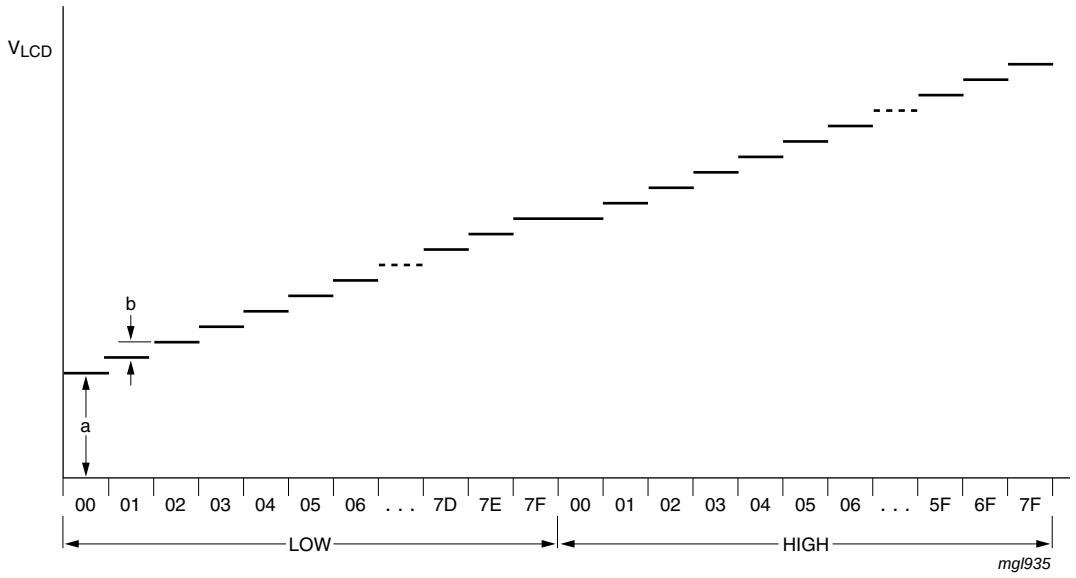
Where V_{th} is the threshold voltage of the liquid crystal material used.

The practical value for V_{LCD} is determined by equating $V_{off(RMS)}$ with a defined LCD threshold voltage (V_{th}), typically when the LCD exhibits approximately 10 % contrast.

As the programming range for the internally generated V_{LCD} allows values above the maximum allowed V_{LCD}, the user must ensure, while setting the VOP register and selecting the temperature compensation, that the V_{LCD} limit maximum of 9.0 V is never exceeded under all conditions and including all tolerances.

Table 10. Parameter values for the HV generator programming

Symbol	Value		Unit
	PRS = 0	PRS = 1	
T_{ints}	27	27	°C
a	2.94	6.75	V
b	0.03	0.03	V
programming range	2.94 to 6.75	6.75 to 10.56	V



VOP[6:0] (programmed) [00h to 7Fh] program range LOW to HIGH.

Fig 12. V_{LCD} programming of PCF8531

9.10 Voltage multiplier control S[1:0]

The PCF8531 incorporates a software configurable voltage multiplier. After reset (internal or external), the voltage multiplier is set to $2 \times V_{DD2}$. The voltage multiplier factors are set by setting bits S[1:0] (see Table 13).

9.11 Temperature compensation

Due to the temperature dependency of the viscosity of the liquid crystals, the LCD controlling voltage V_{LCD} should usually be increased at lower temperatures to maintain optimum contrast. Figure 13 shows V_{LCD} for high multiplex rates.

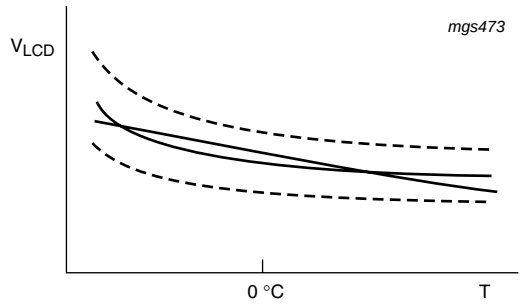


Fig 13. V_{LCD} as a function of liquid crystal temperature

Linear temperature compensation is supported in the PCF8531. The temperature coefficient of V_{LCD} can be selected from eight values by setting bits TC[2:0] (see Table 13).

Table 11. Instruction set

Instruction	I^2C-bus command[1]		I^2C-bus command byte								Description
	RS	R/$\overline{W}$	DB7	DB6	DB5	DB4	DB3	DB2	DB1	DB0	
H1 and H0 = don't care (H independent command page)											
NOP	0	0	0	0	0	0	0	0	0	0	no operation
write data	1	0	D7	D6	D5	D4	D3	D2	D1	D0	write data to display RAM
set default H[1:0]	0	0	0	0	0	0	0	0	0	1	select H[1:0] = 0
H1 = 0 and H0 = 0 (function and RAM command page)											
instruction set	0	0	0	0	0	0	1	0	H1	H0	select command page
function set	0	0	0	0	1	0	0	PD	V	0	power-down control; entry mode
set Y address of RAM	0	0	0	1	0	0	0	Y2	Y1	Y0	set Y address of RAM; $0 \leq Y \leq 5$
set X address of RAM	0	0	1	X6	X5	X4	X3	X2	X1	X0	set X address of RAM; $0 \leq X \leq 127$
H1 = 0 and H0 = 1 (display setting command page)											
multiplex rate	0	0	0	0	0	0	0	1	M1	M0	set multiplex rate
display control	0	0	0	0	0	0	1	D	IM	E	set display configuration
bias system	0	0	0	0	0	1	0	BS2	BS1	BS0	set bias system (BSx)
H1 = 1 and H0 = 0 (HV-gen command page)											
HV-gen control	0	0	0	0	0	0	0	1	PRS	HVE	set V_{LCD} programming range
HV-gen configuration	0	0	0	0	0	0	1	0	S1	S0	set voltage multiplication factor

Table 11. Instruction set *…continued*

Instruction	I²C-bus command[1]		I²C-bus command byte								Description
	RS	R/$\overline{W}$	DB7	DB6	DB5	DB4	DB3	DB2	DB1	DB0	
temperature control	0	0	0	0	1	0	0	TC2	TC1	TC0	set temperature coefficient
test modes	0	0	0	1	X	X	X	X	X	X	do not use (reserved for test)
V_{LCD} control	0	0	1	VOP6	VOP5	VOP4	VOP3	VOP2	VOP1	VOP0	set V_{LCD} register

[1] R/$\overline{W}$ is set to the slave address byte; Co and RS are set in the control byte.

Table 12. Explanation for symbols in Table 11

Bit		0	1
PD		chip is active	chip is in power-down mode
V		horizontal addressing	vertical addressing
IM		normal mode; full display + icons	icon mode; only icons are displayed
H[1:0]	[1]	see Table 13	
D and E		see Table 13	
HVE		voltage multiplier disabled	voltage multiplier enabled
PRS		V_{LCD} programming range LOW	V_{LCD} programming range HIGH
TC[2:0]		see Table 13	
S[1:0]		see Table 13	

[1] The bits H[1:0] identify the command page (use set default H[1:0] command to set H[1:0] = 0).

Table 13. Description of bits H, D and E, TC and S

Bits	Value	Description
Command page (H)		
H[1:0]	00	function and RAM command page
	01	display setting command page
	10	HV-gen command page
Display modes (D, E)		
D and E	00	display blank
	10	normal mode
	01	all display segments
	11	inverse video mode

Table 13. Description of bits H, D and E, TC and S *...continued*

Bits	Value	Description
Temperature coefficient (TC)		
TC[2:0]	000	temperature coefficient TC_0
	001	temperature coefficient TC_1
	010	temperature coefficient TC_2
	011	temperature coefficient TC_3
	100	temperature coefficient TC_4
	101	temperature coefficient TC_5
	110	temperature coefficient TC_6
	111	temperature coefficient TC_7
Voltage multiplier factor (S)		
S[1:0]	00	2 × voltage multiplier
	01	3 × voltage multiplier
	10	4 × voltage multiplier
	11	5 × voltage multiplier

10. I²C-bus interface

10.1 Characteristics of the I²C-bus

The I²C-bus is for bidirectional, two-line communication between different ICs or modules. The two lines are a Serial DAta line (SDA) and a Serial CLock line (SCL). Both lines must be connected to a positive supply via a pull-up resistor. Data transfer may be initiated only when the bus is not busy.

10.1.1 Bit transfer

One data bit is transferred during each clock pulse. The data on the SDA line must remain stable during the HIGH period of the clock pulse as changes in the data line at this time will be interpreted as a control signal (see Figure 14).

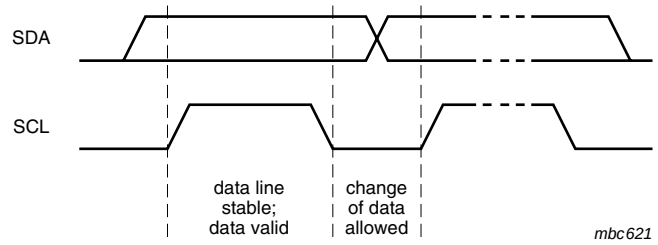


Fig 14. Bit transfer

10.1.2 START and STOP conditions

Both data and clock lines remain HIGH when the bus is not busy. A HIGH-to-LOW transition of the data line, while the clock is HIGH is defined as the START condition (S). A LOW-to-HIGH transition of the data line while the clock is HIGH is defined as the STOP condition (P). The START and STOP conditions are shown in Figure 15.

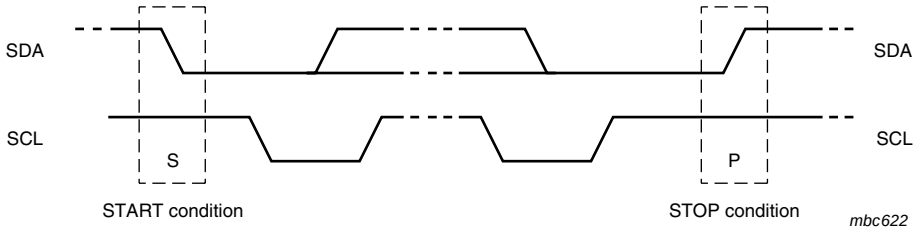


Fig 15. Definition of START and STOP conditions

10.1.3 System configuration

The system configuration is shown in Figure 16.

- Transmitter: the device that sends the data to the bus
- Receiver: the device that receives the data from the bus
- Master: the device that initiates a transfer, generates clock signals and terminates a transfer
- Slave: the device addressed by a master

- Multi-master: more than one master can attempt to control the bus at the same time without corrupting the message
- Arbitration: procedure to ensure that, if more than one master simultaneously tries to control the bus, only one is allowed to do so and the message is not corrupted
- Synchronization: procedure to synchronize the clock signals of two or more devices.

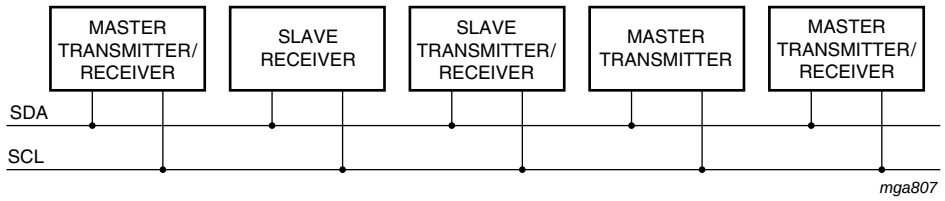


Fig 16. System configuration

10.1.4 Acknowledge

The number of data bytes transferred between the START and STOP conditions from transmitter to receiver is unlimited. Each byte of eight bits is followed by an acknowledge cycle.

- A slave receiver which is addressed must generate an acknowledge after the reception of each byte.
- Also a master receiver must generate an acknowledge after the reception of each byte that has been clocked out of the slave transmitter.
- The device that acknowledges must pull-down the SDA line during the acknowledge clock pulse, so that the SDA line is stable LOW during the HIGH period of the acknowledge related clock pulse (set-up and hold times must be taken into consideration).
- A master receiver must signal an end of data to the transmitter by not generating an acknowledge on the last byte that has been clocked out of the slave. In this event the transmitter must leave the data line HIGH to enable the master to generate a STOP condition.

Acknowledgement on the I^2C-bus is shown in Figure 17.

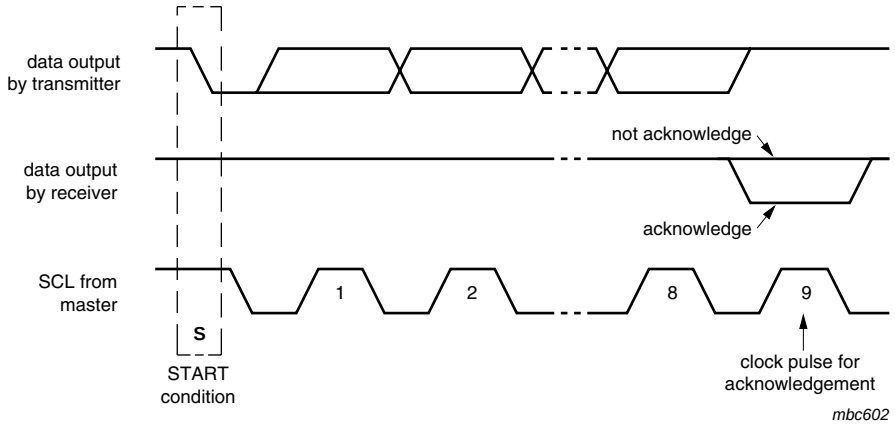


Fig 17. Acknowledge on the I²C-bus

10.2 I²C-bus protocol

This driver does not support read. The PCF8531 is a slave receiver. Therefore, it only responds when R/$\overline{W}$ = 0 in the slave address byte.

Before any data is transmitted on the I²C-bus, the device that must respond is addressed first. Two 7-bit slave addresses (0111100 and 0111101) are reserved for the PCF8531. The least significant bit of the slave address is set by connecting the input SA0 to either logic 0 (V_{SS}) or logic 1 (V_{DD}).

The I²C-bus protocol is shown in Figure 18.

The sequence is initiated with a START condition (S) from the I²C-bus master, and is followed by the slave address. All slaves with the corresponding address acknowledge in parallel, all others ignore the I²C-bus transfer. After acknowledgement, one or more command words follow, which define the status of the addressed slaves. A command word consists of a control byte, which defines Co and RS, plus a data byte (see Figure 19 and Table 11).

The last control byte is tagged with a cleared most significant bit, the continuation bit Co. The control and data bytes are also acknowledged by all addressed slaves on the bus.

After the last control byte, depending on the RS bit setting, either a series of display data bytes or command data bytes may follow. If the RS bit was set logic 1, these display bytes are stored in the display RAM at the address specified by the data pointer.

The data pointer is automatically updated and the data is directed to the intended PCF8531 device. If the RS bit of the last control byte was set logic 0, these command bytes will be decoded and the setting of the device will be changed according to the received commands. The acknowledgement after each byte is made only by the addressed PCF8531. At the end of the transmission, the I²C-bus master issues a STOP condition (P).

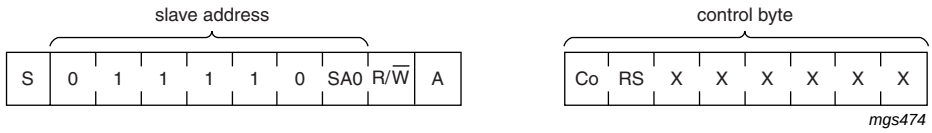


Fig 18. Slave address and control byte

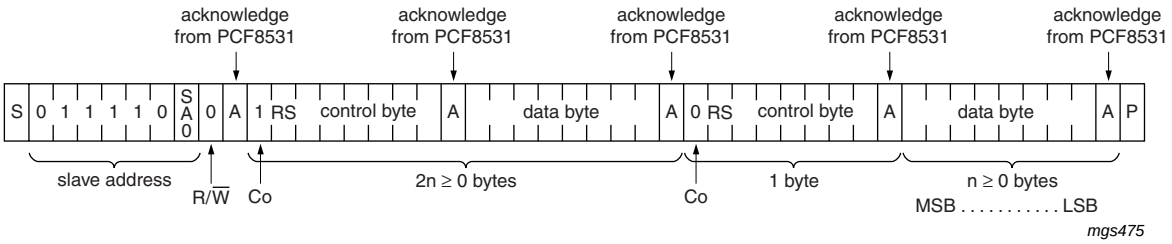


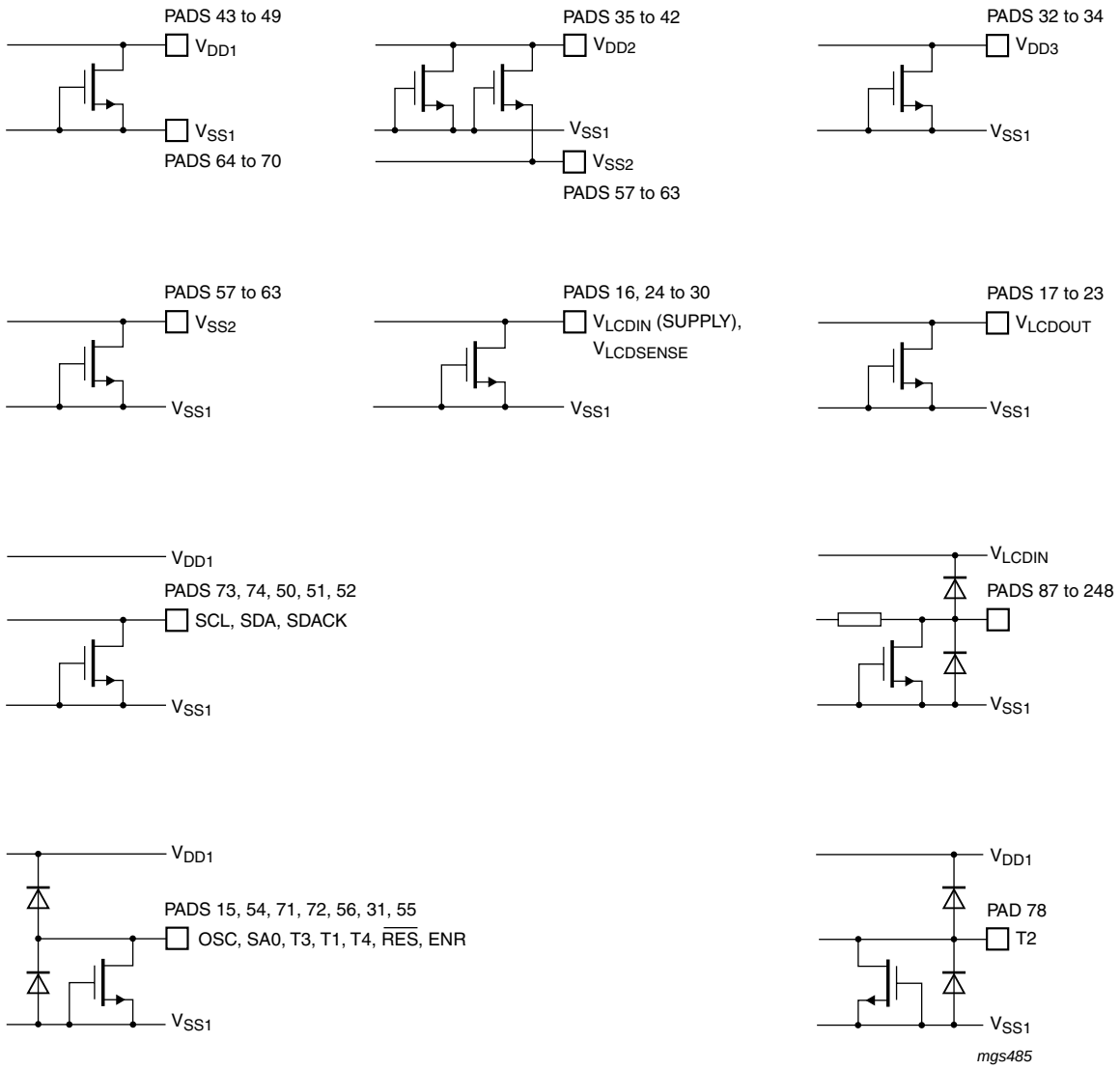
Fig 19. Master transmits to slave receiver; write mode

10.3 Command decoder

The command decoder identifies command words that arrive on the I^2C-bus. The most significant bit of a control byte is the continuation bit Co. If this bit is logic 1, it indicates that only one data byte (either command or RAM data) will follow. If this bit is logic 0, it indicates that a series of data bytes (either command or RAM data) may follow. The DB6 bit of a control byte is the RAM data/command bit RS. When this bit is logic 1, it indicates that another RAM data byte will be transferred next. If the bit is logic 0, it indicates that another command byte will be transferred next.

- Pairs of bytes; information in the second byte, the first byte determines whether information is display or instruction data
- Stream of information bytes after Co = 0; display or instruction data, depending on last RS.

11. Internal circuitry



For all diagrams the maximum forward current is 5 mA and the maximum reverse voltage is 5 V.

Fig 20. Device protection diagrams

12. Limiting values

Table 14. Limiting values [1]

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{DD1}	supply voltage 1	logic supply		–0.5	+5.5	V
V_{DD2}	supply voltage 2	multiplier supply		–0.5	+4.5	V
V_{DD3}	supply voltage 3	multiplier supply		–0.5	+4.5	V
V_{LCD}	LCD supply voltage			–0.5	+9.0	V
V_I	input voltage			–0.5	V_{DD} + 0.5	V
V_O	output voltage			–0.5	V_{DD} + 0.5	V
$I_{DD(LCD)}$	LCD supply current			–50	+50	mA
I_{SS}	ground supply current			–50	+50	mA
I_I	input current			–10	+10	mA
I_O	output current			–10	+10	mA
P_{tot}	total power dissipation			-	300	mW
P/out	power dissipation per output			-	30	mW
V_{ESD}	electrostatic discharge voltage	HBM	[2]	-	±1500	V
		MM	[3]	-	±200	V
I_{lu}	latch-up current		[4]	-	200	mA
T_j	junction temperature			-	+150	°C
T_{stg}	storage temperature		[5]	–65	+150	°C
T_{amb}	ambient temperature	operating device		–40	+85	°C

[1] Parameters are valid over the whole operating temperature range unless otherwise specified. All voltages are referenced to V_{SS} unless otherwise specified.

[2] Pass level; Human Body Model (HBM), according to Ref. 6 “JESD22-A114”.

[3] Pass level; Machine Model (MM), according to Ref. 7 “JESD22-A115”.

[4] Pass level; latch-up testing according to Ref. 8 “JESD78” at maximum ambient temperature ($T_{amb(max)}$).

[5] According to the NXP store and transport requirements (see Ref. 10 “NX3-00092”) the devices have to be stored at a temperature of +8 °C to +45 °C and a humidity of 25 % to 75 %. For long term storage products deviant conditions are described in that document.

13. Static characteristics

Table 15. Static characteristics

V_{DD1} = 1.8 V (1.9 V) to 5.5 V; V_{DD2} and V_{DD3} = 2.5 V to 4.5 V; $V_{SS1} = V_{SS2}$ = 0 V; V_{DD1} to $V_{DD3} \leq V_{LCD} \leq 9.0$ V; T_{amb} = −40 °C to +85 °C; unless otherwise specified.

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
Supplies							
V_{LCD}	LCD supply voltage		[1]	4.0	-	9.0	V
		icon mode	[1]	3.0	-	9.0	V
V_{DD1}	supply voltage 1	logic supply		1.9	-	5.5	V
		$T_{amb} \geq -25$ °C		1.8	-	5.5	V
V_{DD2}	supply voltage 2	multiplier supply; LCD voltage internally generated		2.5	-	4.5	V
V_{DD3}	supply voltage 3	multiplier supply; LCD voltage internally generated		2.5	-	4.5	V
I_{DD}	supply current	power-down mode; internal V_{LCD}		-	2	10	µA
		normal mode; internal V_{LCD}	[2][3]	-	170	350	µA
		normal mode; external V_{LCD}	[2]	-	10	50	µA
$I_{DD(LCD)}$	LCD supply current	normal mode; external V_{LCD}	[2][4]	-	25	100	µA
		icon mode; external V_{LCD}	[2][5]	-	15	70	µA
V_{POR}	power-on reset voltage		[6]	0.9	1.2	1.6	V
Logic							
V_{IL}	LOW-level input voltage			V_{SS}	-	$0.3V_{DD}$	V
V_{IH}	HIGH-level input voltage			$0.7V_{DD}$	-	V_{DD}	V
$I_{OL(SDA)}$	LOW-level output current on pin SDA	V_{OL} = 0.4 V; V_{DD} = 5.0 V		3.0	-	-	mA
I_{LI}	input leakage current	$V_I = V_{DD}$ or V_{SS}		−1	-	+1	µA
Column and row outputs							
R_O	output resistance	column outputs: C0 to C127	[7]	-	12	20	kΩ
		row outputs: R0 to R33		-	12	20	kΩ
ΔV_{bias}	bias voltage variation	outputs R0 to R33 and C0 to C127		−100	0	+100	mV
ΔV_{LCD}	LCD voltage variation	TC_1 to TC_7	[8]	-	-	±3.9	%
TC	temperature coefficient	T_{amb} = −20 °C to +70 °C					
		TC_0; TC[2:0] = 000		-	0	-	%/K
		TC_1; TC[2:0] = 001		-	−0.026	-	%/K
		TC_2; TC[2:0] = 010		-	−0.039	-	%/K
		TC_3; TC[2:0] = 011		-	−0.052	-	%/K
		TC_4; TC[2:0] = 100		-	−0.078	-	%/K
		TC_5; TC[2:0] = 101		-	−0.13	-	%/K
		TC_6; TC[2:0] = 110		-	−0.19	-	%/K
		TC_7; TC[2:0] = 111		-	−0.26	-	%/K
T_{ints}	intersection temperature			-	27	-	°C

[1] As the programming range for the internally generated V_{LCD} allows values above the maximum allowed V_{LCD}, the user must ensure, while setting the VOP register and selecting the temperature compensation, that the V_{LCD} maximum limit of 9 V will never be exceeded under all conditions and including all tolerances.

[2] LCD outputs are open circuit, inputs at V_{DD} or V_{SS}; bus inactive.

[3] V_{DD1} to V_{DD3} = 2.85 V; V_{LCD} = 7.0 V; voltage multiplier = 3 × V_{DD}; f_{osc} = 34 kHz.

[4] V_{DD1} to V_{DD3} = 2.75 V; V_{LCD} = 9.0 V; f_{osc} = 34 kHz.

[5] V_{DD1} to V_{DD3} = 2.75 V; V_{LCD} = 3.5 V; f_{osc} = 34 kHz.

[6] Resets all logic when $V_{DD1} < V_{POR}$.

[7] $I_{load} \leq 50$ μA; outputs are tested one at a time.

[8] $V_{LCD} \leq 7.7$ V.

14. Dynamic characteristics

Table 16. Dynamic characteristics

V_{DD1} = 1.8 V (1.9 V) to 5.5 V; V_{DD2} and V_{DD3} = 2.5 V to 4.5 V; $V_{SS1} = V_{SS2}$ = 0 V; V_{DD1} to $V_{DD3} \leq V_{LCD} \leq 9.0$ V; T_{amb} = −40 °C to +85 °C; unless otherwise specified.

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
$f_{fr(LCD)}$	LCD frame frequency	V_{DD} = 3.0 V	[1]	40	66	135	Hz
f_{osc}	oscillator frequency			20	34	65	kHz
$f_{clk(ext)}$	external clock frequency			20	-	65	kHz
$t_{w(RESL)}$	RES LOW pulse width		[2]	300	-	-	ns
$t_{su(RESL)}$	RES LOW set-up time			-	-	30	μs
Serial bus interface (see Figure 22)[3]							
f_{SCL}	SCL clock frequency			0	-	400	kHz
t_{LOW}	LOW period of the SCL clock			1.3	-	-	μs
t_{HIGH}	HIGH period of the SCL clock			0.6	-	-	μs
$t_{SU;DAT}$	data set-up time			100	-	-	ns
$t_{HD;DAT}$	data hold time			0	-	0.9	ns
t_r	rise time of both SDA and SCL signals		[4]	20 + 0.1C_b	-	0.3	μs
t_f	fall time of both SDA and SCL signals		[4]	20 + 0.1C_b	-	0.3	μs
C_b	capacitive load for each bus line			-	-	400	pF
$t_{SU;STA}$	set-up time for a repeated START condition			0.6	-	-	μs
$t_{HD;STA}$	hold time (repeated) START condition			0.6	-	-	μs
$t_{SU;STO}$	set-up time for STOP condition			0.6	-	-	μs
t_{SP}	pulse width of spikes that must be suppressed by the input filter	on bus		-	-	50	ns
t_{BUF}	bus free time between a STOP and START condition			1.3	-	-	μs

[1] $f_{fr} = f_{clk(ext)}/480$ or $f_{osc}/480$.

[2] A reset is generated if $t_{w(RESL)} > 3$ ns (see Figure 21).

[3] All timing values are valid within the operating supply voltage and ambient temperature range and are referenced to V_{IL} and V_{IH}, with an input voltage swing of V_{SS} to V_{DD}.

[4] C_b = total capacitance of one bus line in pF.

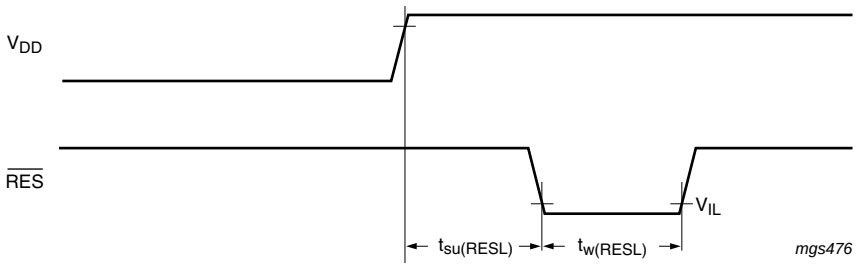


Fig 21. Reset timing

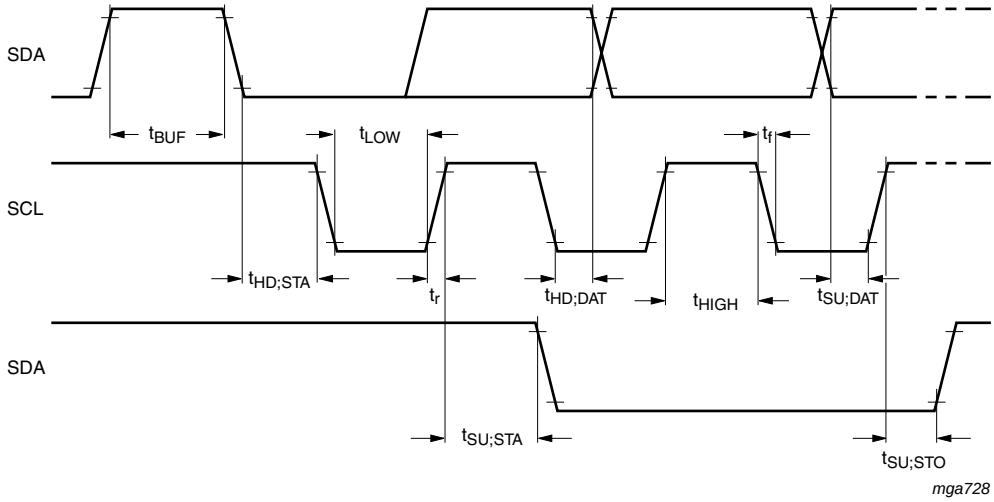
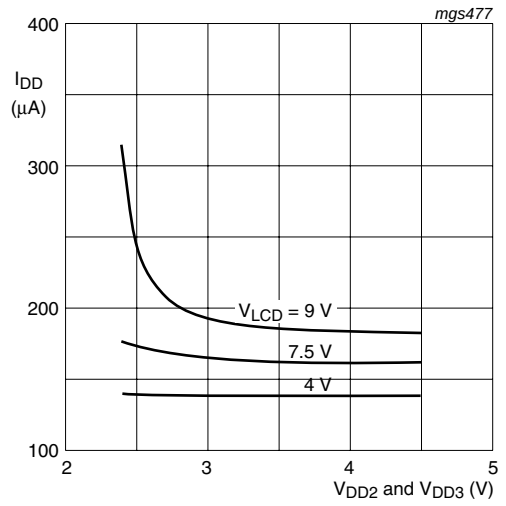
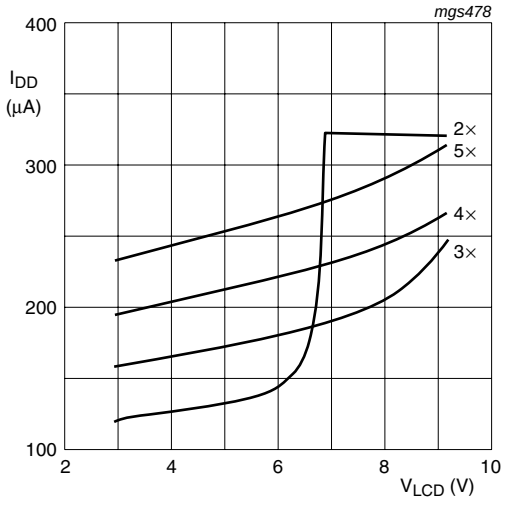


Fig 22. I^2C-bus timing



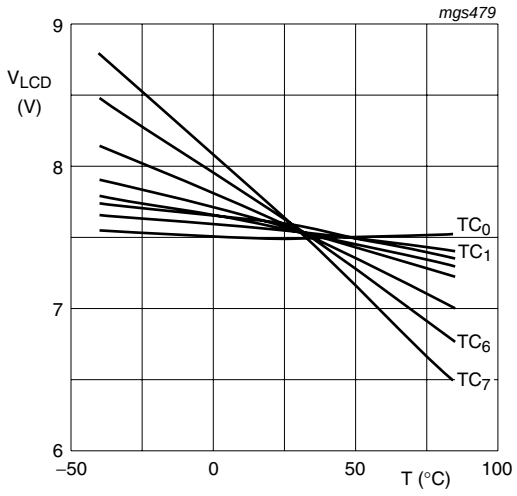
V_{DD1} = 2 V; 4 × voltage multiplier; T_{amb} = 27 °C; TC = 0; BS = 100; no V_{LCD} load.

Fig 23. Supply current as a function of supply voltage 2 and supply voltage 3



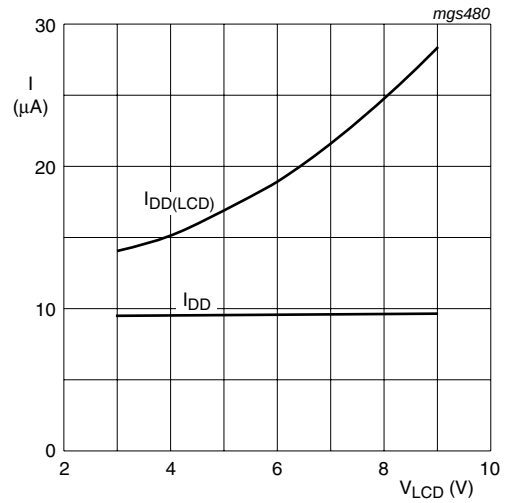
V_{DD1} = 1.8 V; V_{DD2} and V_{DD3} = 2.6 V; T_{amb} = 27 °C; f_{osc} = 34 kHz; no V_{LCD} load.

Fig 24. Supply current as a function of LCD supply voltage; different multiplication factors



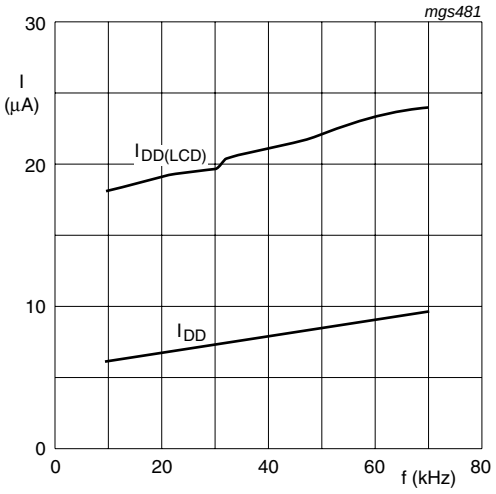
V_{LCD} = 7.5 V; V_{DD1} to V_{DD3} = 2.7 V; T_{amb} = 27 °C; no V_{LCD} load.

Fig 25. LCD supply voltage as a function of temperature



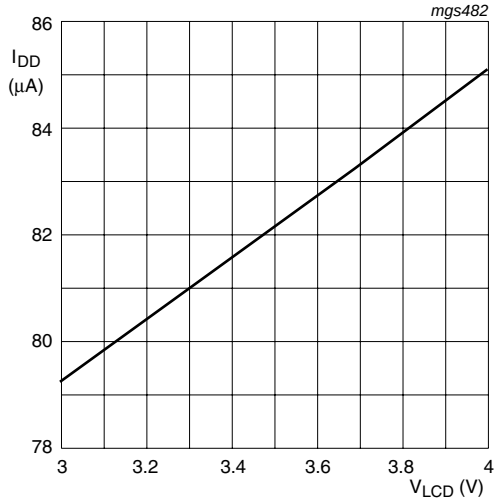
V_{DD1} = 1.8 V; V_{DD2} and V_{DD3} = 2.5 V; external V_{LCD}; T_{amb} = 27 °C; TC = 0; BS = 100; no V_{LCD} load.

Fig 26. Supply current as a function of LCD supply voltage



V_{DD1} = 2.5 V; V_{DD2} and V_{DD3} = 2.5 V; external V_{LCD}; T_{amb} = 27 °C; TC = 0; BS = 100; no V_{LCD} load.

Fig 27. Supply current as a function of frequency



V_{DD1} = 1.8 V; V_{DD2} = 2.5 V; 2 × voltage multiplier; T_{amb} = 27 °C; TC = 0; BS = 111; no V_{LCD} load.

Fig 28. Supply current as a function of LCD supply voltage

15. Application information

15.1 Typical system configuration

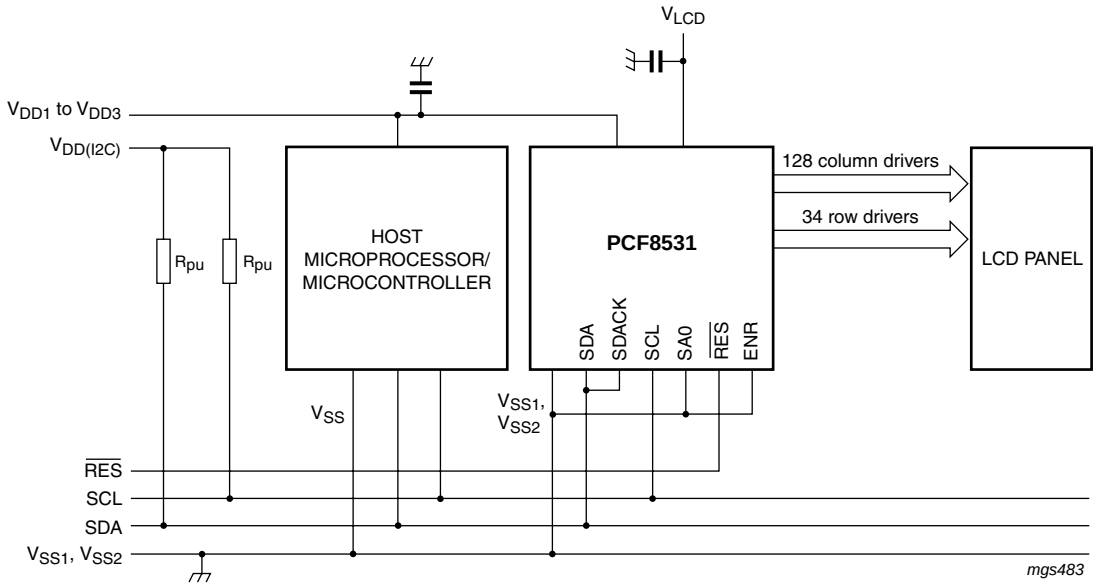


Fig 29. Typical system configuration

The host microprocessor/microcontroller and the PCF8531 are both connected to the I²C-bus. The SDA and SCL lines must be connected to the positive power supply via pull-up resistors. The internal oscillator requires no external components. The appropriate intermediate biasing voltage for the multiplexed LCD waveforms are generated on-chip. The only other connections required to complete the system are to the power supplies (V_{DD}, V_{SS}, and V_{LCD}) and suitable capacitors for decoupling V_{LCD} and V_{DD}.

15.2 Power supply connections for internal V_{LCD} generation

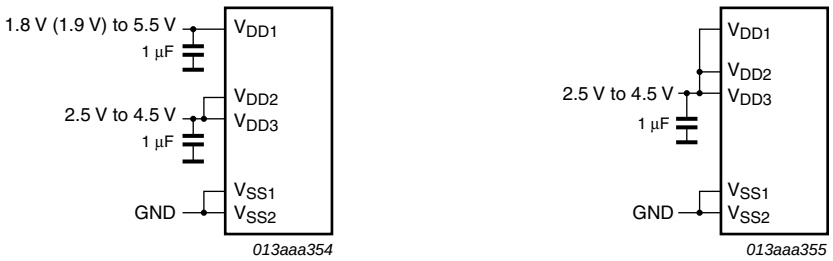


Fig 30. Recommended V_{DD} connections for internal V_{LCD} generation

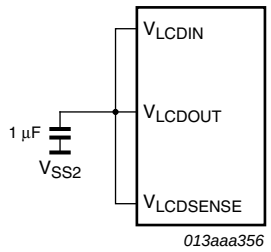
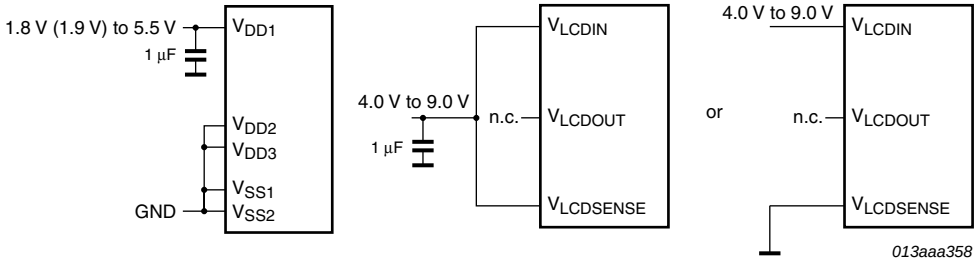


Fig 31. Recommended V_{LCD} connections for internal V_{LCD} generation

15.3 Power supply connections for external V_{LCD} generation



Remark: When using an external V_{LCD}, the internal V_{LCD} generator **must never** be switched on otherwise damages will occur.

Fig 32. Recommended V_{DD} connections for external V_{LCD} generation

15.4 Information about V_{LCD} connections

V_{LCDIN} — This input is used for generating the 5 LCD bias levels. It is the power supply for the bias level buffers.

V_{LCDOUT} — This is the V_{LCD} output if V_{LCD} is generated internally. It is the output of the charge pump. In this case pin V_{LCDOUT} must be connected to V_{LCDIN} and to $V_{LCDSENSE}$ (see Figure 31). V_{LCDOUT} must be left open circuit when V_{LCD} is supplied from an external source (see Figure 32).

$V_{LCDSENSE}$ — When using the internal V_{LCD} generation, this pin must be connected to V_{LCDOUT} and V_{LCDIN} (see Figure 31). When using an external V_{LCD} supply it must be connected to V_{LCDIN} or to ground (see Figure 32).

15.5 Chip-on-glass application

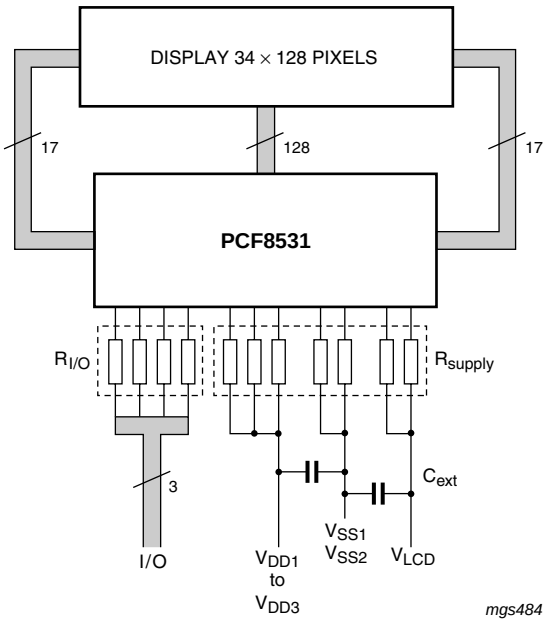


Fig 33. Chip-on-glass application

The required minimum values for the external capacitors in a chip-on-glass application are:

- C_{ext} = 100 nF between V_{LCD} and V_{SS1}, V_{SS2}; C_{ext} = 470 nF between V_{DD1}, V_{DD2}, V_{DD3} and V_{SS1}, V_{SS2}.
- Higher capacitor values are recommended for ripple reduction.
- For COG applications, the recommended ITO track resistance must be minimized for the I/O and supply connections. Optimized values for these tracks are below 50 Ω for the supply (R_{supply}) and below 100 Ω for the I/O connections ($R_{I/O}$).
- To reduce the sensitivity of the reset to ESD/EMC disturbances for a COG application, NXP strongly recommended implementing a series input resistance in the reset line (recommended minimum value 8 kΩ) on the glass (ITO). If the reset input is not used, this input must be connected to V_{DD1} using a short connection.

15.6 Programming example

Table 17. Programming example for PCF8531

Step	Serial bus byte								Display	Operation
	DB7	DB6	DB5	DB4	DB3	DB2	DB1	DB0		
1	0	1	1	1	1	0	SA0	0		start; slave address; R/$\overline{W}$ = 0
2	1	0	0	0	0	0	0	0		control byte; Co = 1; RS = 0
3	0	0	0	0	0	0	0	1		H[1:0] independent command; select function and RAM command page (H[1:0] = 00)
4	1	0	0	0	0	0	0	0		control byte; Co = 1; RS = 0
5	0	0	1	0	0	0	1	0		function and RAM command page PD = 0 and V = 1
6	1	0	0	0	0	0	0	0		control byte; Co = 1; RS = 0
7	0	0	0	0	1	0	0	1		function and RAM command page select display setting command page H[1:0] = 01
8	1	0	0	0	0	0	0	0		control byte; Co = 1; RS = 0
9	0	0	0	0	1	1	0	0		display setting command page; set normal mode (D = 1; IM = 0 and E = 0)
10	1	0	0	0	0	0	0	0		control byte; Co = 1; RS = 0
11	0	0	0	0	0	1	0	1		select multiplex rate 1:34
12	1	0	0	0	0	0	0	0		control byte; Co = 1; RS = 0
13	0	0	0	0	0	0	0	1		H[2:0] independent command; select function and RAM command page H[1:0] = 00
14	1	0	0	0	0	0	0	0		control byte; Co = 1; RS = 0
15	0	0	0	0	1	0	1	0		function and RAM command page; select HV-gen command page H[1:0] = 10
16	1	0	0	0	0	0	0	0		control byte; Co = 1; RS = 0
17	0	0	0	0	1	0	1	1		HV-gen command page; select voltage multiplication factor 5 S[1:0] = 11
18	1	0	0	0	0	0	0	0		control byte; Co = 1; RS = 0
19	0	0	1	0	0	0	1	0		HV-gen command page; select temperature coefficient 2 TC[2:0] = 010
20	1	0	0	0	0	0	0	0		control byte; Co = 1; RS = 0
21	0	0	0	0	0	1	1	1		HV-gen command page; select high V_{LCD} programming range (PRS = 1); voltage multiplier off (HVE = 1)
22	1	0	0	0	0	0	0	0		control byte; Co = 1; RS = 0

Table 17. Programming example for PCF8531 *...continued*

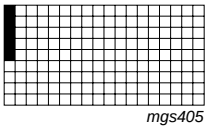
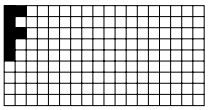
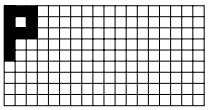
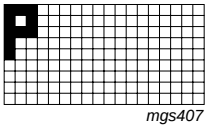
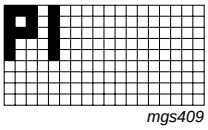
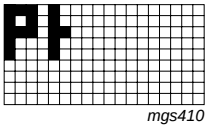
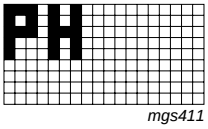
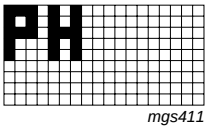
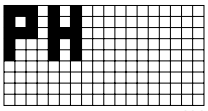
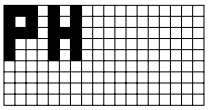
Step	Serial bus byte								Display	Operation
	DB7	DB6	DB5	DB4	DB3	DB2	DB1	DB0		
23	1	0	1	0	0	0	0	0		HV-gen command page; set V_{LCD} = 7.71 V; VOP[6:0] = 0100000
24	0	1	0	0	0	0	0	0		control byte; Co = 0; RS = 1
25	0	0	0	1	1	1	1	1	 mgs405	data write; Y and X are initialized to 0 by default, so they are not set here
26	0	0	0	0	0	1	0	1	 mgs406	data write
27	0	0	0	0	0	1	1	1	 mgs407	data write
28	0	0	0	0	0	0	0	0	 mgs407	data write
29	0	0	0	1	1	1	1	1	 mgs409	data write
30	0	0	0	0	0	1	0	0	 mgs410	data write
31	0	0	0	1	1	1	1	1	 mgs411	data write; last data and stop transmission
32	0	1	1	1	1	0	SA0	0	 mgs411	repeated start; slave address; R/$\overline{W}$ = 0

Table 17. Programming example for PCF8531 *...continued*

Step	Serial bus byte								Display	Operation
	DB7	DB6	DB5	DB4	DB3	DB2	DB1	DB0		
33	1	0	0	0	0	0	0	0	 mgs411	control byte; Co = 1; RS = 0
34	0	0	0	0	0	0	0	1		H[1:0] independent command; select function and RAM command page H[1:0] = 00
35	1	0	0	0	0	0	0	0		control byte; Co = 1; RS = 0
36	0	0	0	0	1	0	0	1	 mgs411	function and RAM command page; select display setting command page H[1:0] = 01
37	1	0	0	0	0	0	0	0		control byte; Co = 1; RS = 0
38	0	0	0	0	0	0	0	1		H[1:0] independent command; select function and RAM command page H[1:0] = 00
39	1	0	0	0	0	0	0	0		control byte; Co = 1; RS = 0
40	0	0	0	0	1	1	0	1	 mgs412	display control; set inverse video mode (D = 1; E = 1 and IM = 0)
41	1	0	0	0	0	0	0	0	 mgs412	control byte; Co = 1; RS = 0
42	1	0	0	0	0	0	0	0	 mgs412	set X address of RAM; set address to ‘0000000’
43	0	1	0	0	0	0	0	0	 mgs412	control byte; Co = 0; RS = 1
44	0	0	0	0	0	0	0	0	 mgs414	data write

16. Package outline

Not applicable.

17. Handling information

All input and output pins are protected against ElectroStatic Discharge (ESD) under normal handling. When handling Metal-Oxide Semiconductor (MOS) devices ensure that all normal precautions are taken as described in *JESD625-A*, *IEC 61340-5* or equivalent standards.

18. Packing information

Table 18. Tray dimensions (see Figure 34)

Symbol	Description	Value
A	pocket pitch in x direction	13.72 mm
B	pocket pitch in y direction	4.17 mm
C	pocket width in x direction	12.34 mm
D	pocket width in y direction	2.05 mm
E	tray width in x direction	50.8 mm
F	tray width in y direction	50.8 mm
x	number of pockets, x direction	3
y	number of pockets, y direction	10

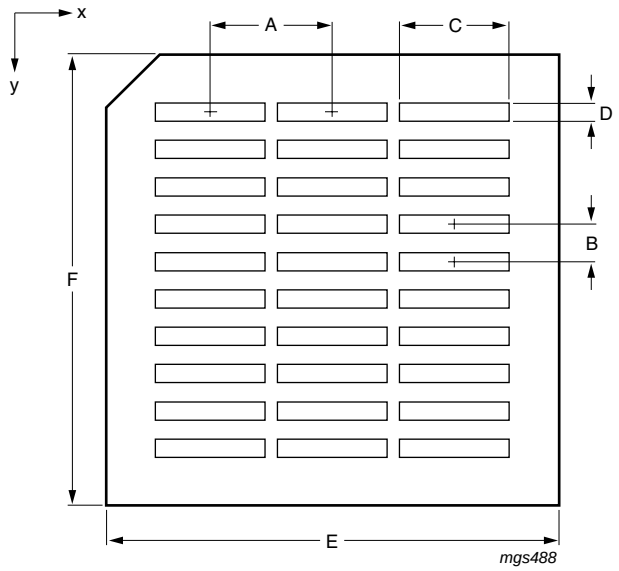
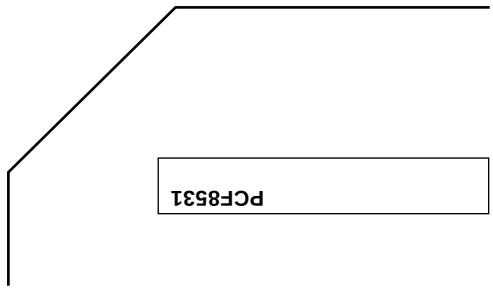


Fig 34. Tray details



The orientation of the IC in a pocket is indicated by the position of the IC type name on the die surface with respect to the chamfer on the upper left corner of the tray. Refer to the bonding pad location diagram (Figure 2) for the orientation and position of the type name on the die surface.

Fig 35. Tray alignment

19. Abbreviations

Table 19. Abbreviations

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal-Oxide Semiconductor
COG	Chip-On-Glass
DDRAM	Double Data Random Access Memory
EMC	ElectroMagnetic Compatibility
ESD	ElectroStatic Discharge
HBM	Human Body Model
HV	High Voltage
IC	Integrated Circuit
ITO	Indium Tin Oxide
LCD	Liquid Crystal Display
LSB	Least Significant Bit
MM	Machine Model
MPU	MicroProcessor Unit
POR	Power-On Reset
RAM	Random Access Memory
RC	Resistance-Capacitance
TC	Temperature Coefficient
SCL	Serial CLock line
SDA	Serial DAta line

20. References

[1] **AN10170 —** Design guidelines for COG modules with NXP monochrome LCD drivers

[2] **AN10706 —** Handling bare die

[3] **AN10853 —** ESD and EMC sensitivity of IC

[4] **IEC 60134 —** Rating systems for electronic tubes and valves and analogous semiconductor devices

[5] **IEC 61340-5 —** Protection of electronic devices from electrostatic phenomena

[6] **JESD22-A114 —** Electrostatic Discharge (ESD) Sensitivity Testing Human Body Model (HBM)

[7] **JESD22-A115 —** Electrostatic Discharge (ESD) Sensitivity Testing Machine Model (MM)

[8] **JESD78 —** IC Latch-Up Test

[9] **JESD625-A —** Requirements for Handling Electrostatic-Discharge-Sensitive (ESDS) Devices

[10] **NX3-00092 —** NXP store and transport requirements

[11] **UM10204 —** I^2C-bus specification and user manual

21. Revision history

Table 20. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PCF8531 v.6	20110516	Product data sheet	-	PCF8531 v.5
Modifications:	• Specified for product type PCF8531U/2DA/1			
PCF8531 v.5	20100810	Product data sheet	-	PCF8531_4
PCF8531_4	20080613	Product data sheet	-	PCF8531_3
PCF8531_3	20000211	Product data sheet	-	PCF8531_2
PCF8531_2	19990810	Product data sheet	-	PCF8531_SDS_1
PCF8531_SDS_1	19990322	Product data sheet	-	-

22. Legal information

22.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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24. Contents

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